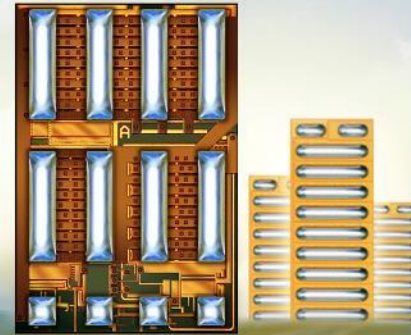


*The eGaN[®] Technology
Journey Continues*



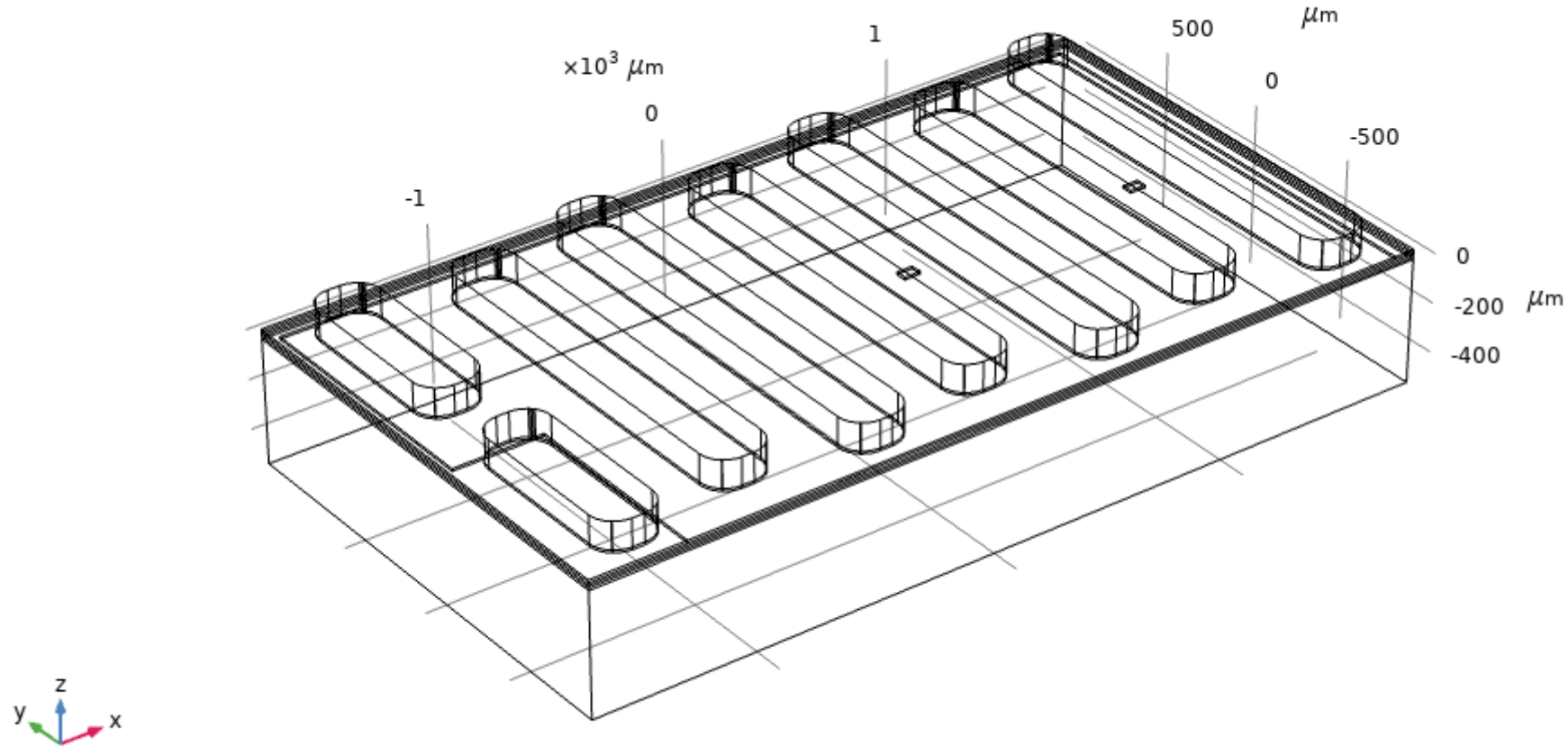
EPC2088 Thermal Model

EPC2088 FEA thermal simulations



- The thermal model applies to EPC2088.
- A power dissipation of 1 W in the device active area is assumed.
- Finite element analysis (FEA) thermal simulations
 - $R_{\theta_{JB}}$ and $R_{\theta_{JC}}$ are obtained by stationary simulations.
 - $Z_{\theta_{JB}}$ and $Z_{\theta_{JC}}$ are obtained by transient simulations.
- R-C thermal model is generated.

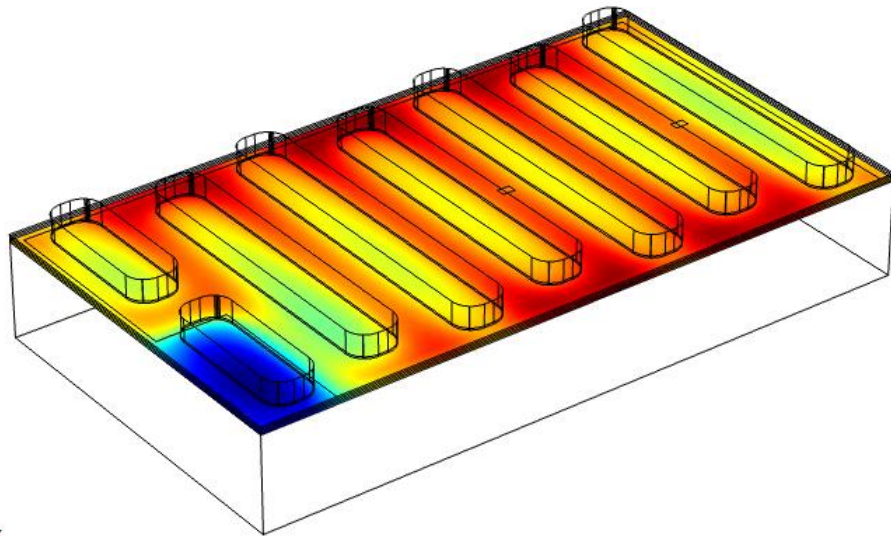
EPC2088 geometry in simulation



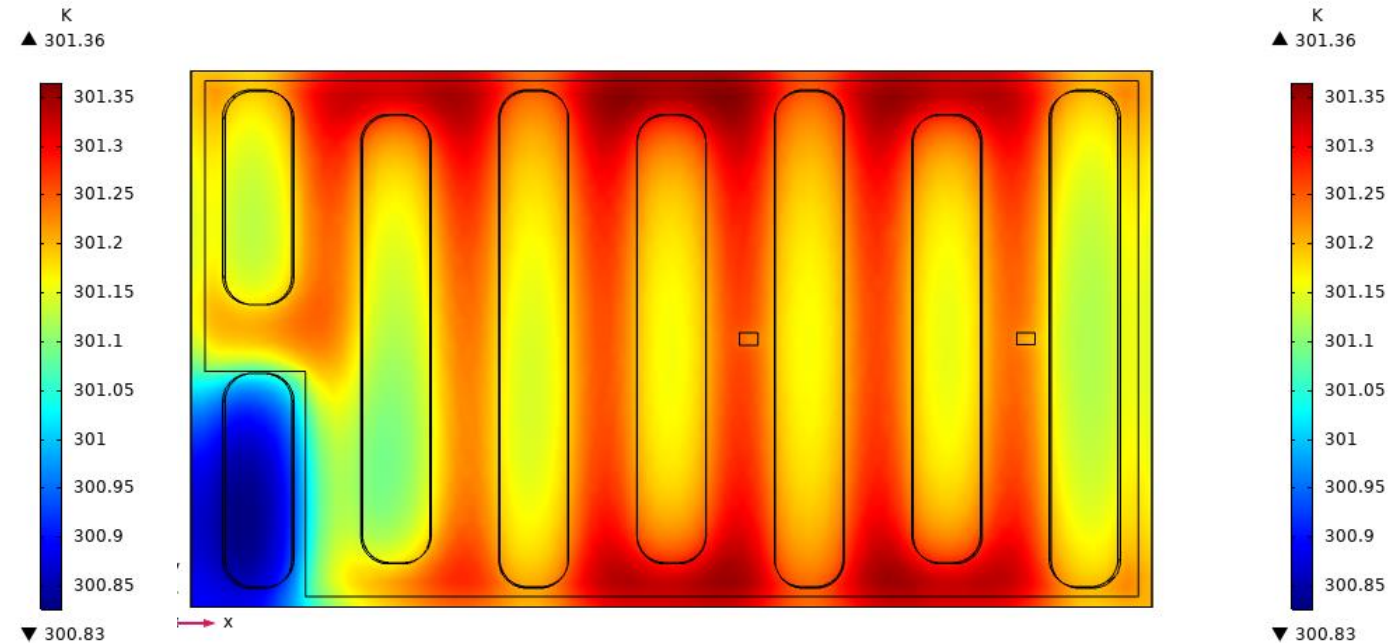
EPC2088 Steady-state $R_{\Theta JB}$

Typical $R_{\Theta JB} = 1.4 \text{ }^{\circ}\text{C/W}$

Volume: Temperature (K)



Volume: Temperature (K)

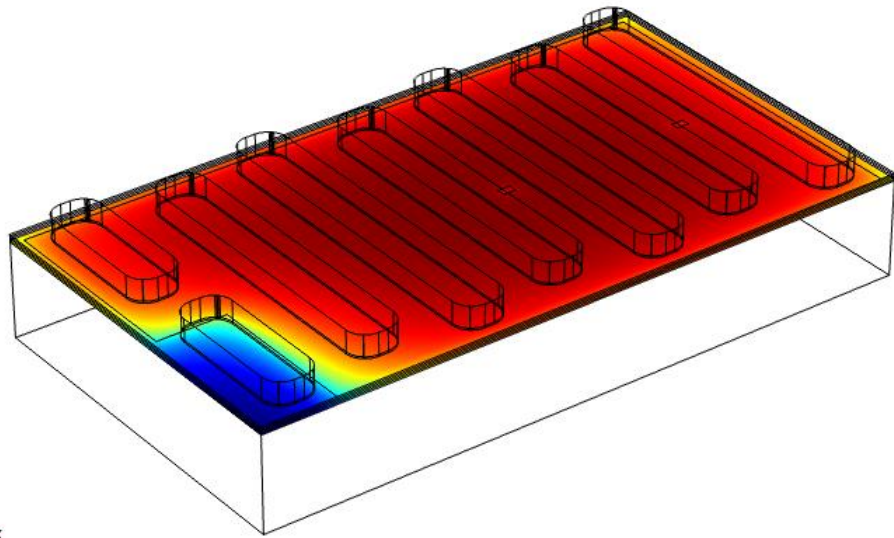


- Operating condition: Power = 1 W in the active area.
- Boundary condition: Temperature of top of solder bumps set to be 300 K.

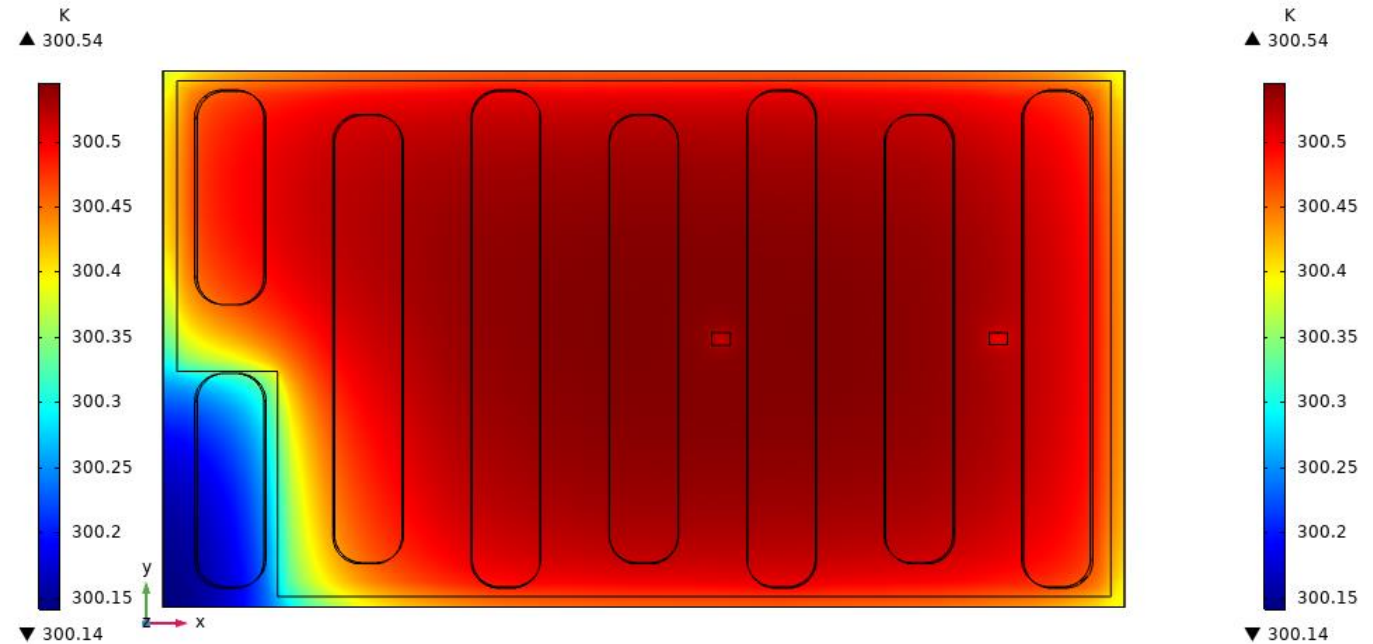
EPC2088 Steady-state $R_{\theta JC}$

Typical $R_{\theta JC} = 0.5 \text{ } ^\circ\text{C/W}$

Volume: Temperature (K)

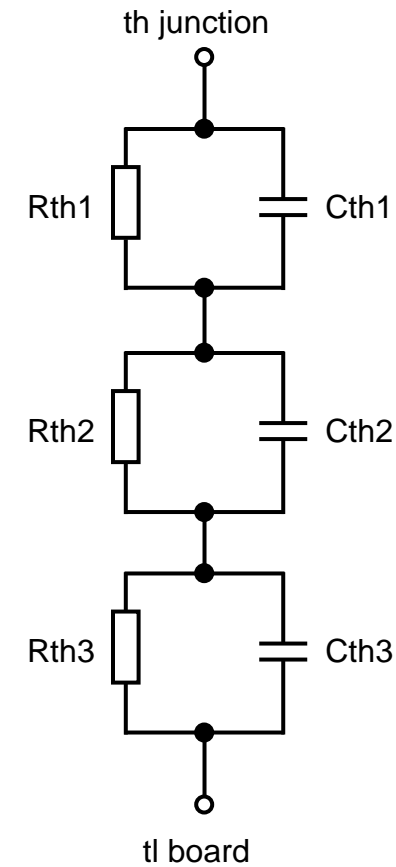
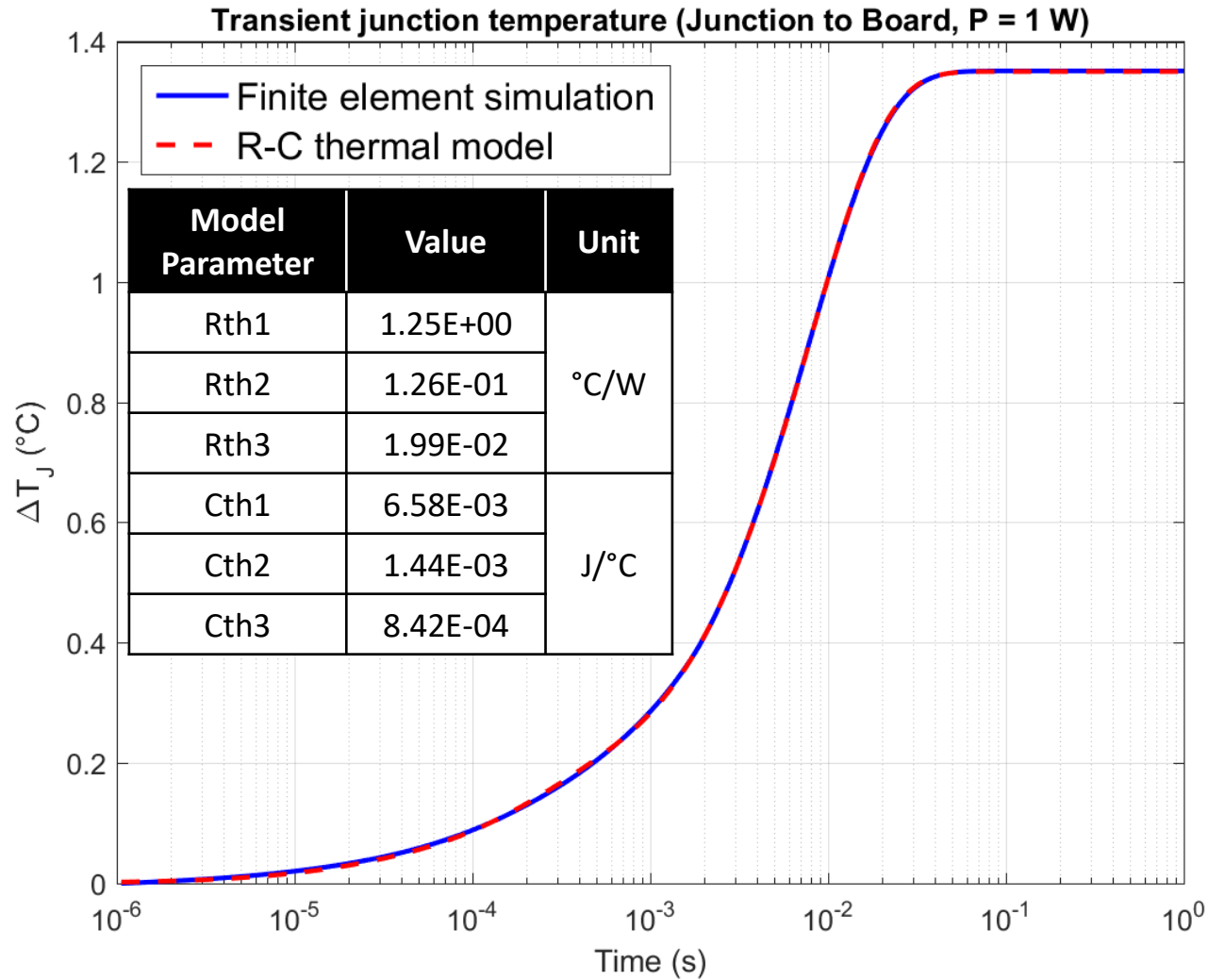


Volume: Temperature (K)



- Operating condition: Power = 1 W in the active area.
- Boundary condition: Temperature of the device backside set to be 300 K.

EPC2088 $Z_{\Theta JB}$ R-C thermal model



EPC2088 $Z_{\Theta JC}$ R-C thermal model

